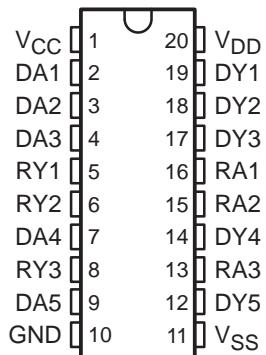


- Single-Chip RS-232 Interface for an External Modem or Other Computer Peripheral Serial Port
- Designed to Transmit and Receive 4- μ s Pulses (Equivalent to 256 kbit/s)
- Wide Driver Supply-Voltage Range: 4.75 V to 15 V
- Driver Output Slew Rates Are Controlled Internally to 30 V/ μ s Maximum
- Receiver Input Hysteresis . . . 1000 mV Typical
- RS-232 Bus-Pin ESD Protection Exceeds 15 kV Using Human-Body Model (HBM)
- Five Drivers and Three Receivers Meet or Exceed the Requirements of TIA/EIA-232-F and ITU v.28 Standards
- Complements the SN75LP1185
- Designed to Replace the Industry-Standard SN75196 With the Same Flow-Through Pinout
- Package Options Include Plastic Small Outline (DW), Shrink Small-Outline (DB), Thin Shrink Small-Outline (PW), and Dual-in-Line (N) Packages

DB, DW, N, OR PW PACKAGE
(TOP VIEW)



description

The SN75LP196 is a low-power bipolar device containing five drivers and three receivers, with 15 kV of ESD protection on the bus pins with respect to each other. Bus pins are defined as those pins that tie directly to the serial-port connector, including GND. The pinout matches the flow-through design of the industry-standard SN75196 and allows easy interconnection of the UART and serial-port connector of the IBM PC/AT and compatibles. This device provides a rugged, low-cost solution for this function with the combination of bipolar processing and 15-kV ESD protection.

The SN75LP196 has internal slew-rate control to provide a maximum rate of change in the output signal of 30 V/ μ s. The driver output swing is clamped nominally at ± 6 V to enable the higher data rates associated with this device and to reduce EMI emissions. Even though the driver outputs are clamped, they can handle voltages up to ± 15 V without damage. All the logic inputs can accept 3.3-V or 5-V input signals.

The SN75LP196 complies with the requirements of the TIA/EIA-232-F and the ITU v.28 standards. These standards are for data interchange between a host computer and peripheral at signaling rates up to 20 kbit/s. The switching speeds of the SN75LP196 support rates up to 256 kbit/s with lower capacitive loads (shorter cables).

The SN75LP196 is characterized for operation from 0°C to 70°C.



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SN75LP196 LOW-POWER MULTIPLE RS-232 DRIVERS AND RECEIVERS

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Function Tables

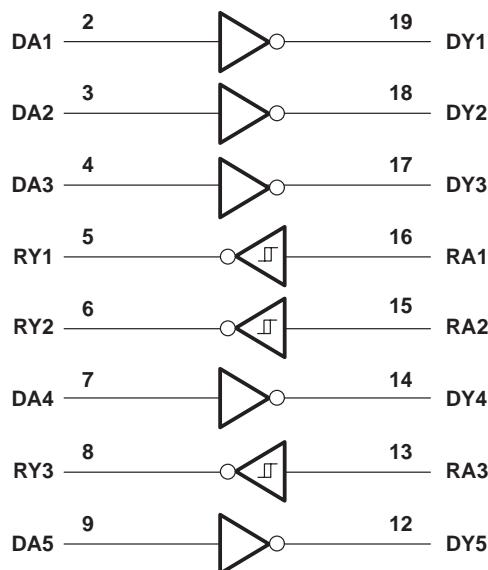
DRIVER

INPUT DA	OUTPUT DY
H	L
L	H
Open	L

RECEIVER

INPUT RA	OUTPUT RY
H	L
L	H
Open	H

logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltage values are with respect to network ground terminal, unless otherwise noted.

2. Per MIL-STD-883 Method 3015.7
3. Maximum power dissipation is a function of $T_J(\max)$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(\max) - T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can impact reliability.
4. The package thermal impedance is calculated in accordance with JESD 51, except for through-hole packages, which use a trace length of zero.

recommended operating conditions

			MIN	NOM	MAX	UNIT
V _{CC}	Supply voltage (see Note 5)		4.75	5	5.25	V
V _{DD}	Supply voltage (see Note 6)		9	12	15	V
V _{SS}	Supply voltage (see Note 6)		-9	-12	-15	V
V _{IH}	High-level input voltage	DA	2			V
V _{IL}	Low-level input voltage	DA			0.8	V
V _I	Receiver input voltage	RA	-25	25		V
I _{OH}	High-level output current	RY			-1	mA
I _{OL}	Low-level output current	RY			2	mA
T _A	Operating free-air temperature		0	70		°C

NOTES: 5. V_{CC} cannot be greater than V_{DD} .
6. The device operates down to $V_{DD} = V_{CC}$ and $|V_{SS}| = V_{CC}$, but supply currents increase and other parameters may vary slightly from the data-sheet limits.



SN75LP196

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supply currents over the recommended operating conditions (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Supply current for V_{CC} , I_{CC}	No load, All inputs at minimum V_{OH} or maximum V_{OL}	$V_{DD} = 9 \text{ V}$, $V_{SS} = -9 \text{ V}$		1000	μA
		$V_{DD} = 12 \text{ V}$, $V_{SS} = -12 \text{ V}$		1000	
Supply current for V_{DD} , I_{DD}	All inputs at minimum V_{OH} or maximum V_{OL}	$V_{DD} = 9 \text{ V}$, $V_{SS} = -9 \text{ V}$		800	μA
		$V_{DD} = 12 \text{ V}$, $V_{SS} = -12 \text{ V}$		800	
Supply current for V_{SS} , I_{SS}	$V_{DD} = 9 \text{ V}$, $V_{SS} = -9 \text{ V}$ $V_{DD} = 12 \text{ V}$, $V_{SS} = -12 \text{ V}$			-800	μA
				-800	

driver electrical characteristics over the recommended operating conditions (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{OH} High-level output voltage	$V_{IL} = 0.8 \text{ V}$, $R_L = 3 \text{ k}\Omega$, See Figure 1	$V_{DD} = 9 \text{ V}$, $V_{SS} = -9 \text{ V}$, See Note 7	5	5.8	6.6
		$V_{DD} = 12 \text{ V}$, $V_{SS} = -12 \text{ V}$, See Note 8	5	5.8	6.6
V_{OL} Low-level output voltage	$V_{IH} = 2 \text{ V}$, $R_L = 3 \text{ k}\Omega$, See Figure 1	$V_{DD} = 9 \text{ V}$, $V_{SS} = -9 \text{ V}$, See Note 7	-5	-5.8	-6.9
		$V_{DD} = 12 \text{ V}$, $V_{SS} = -12 \text{ V}$, See Note 8	-5	-5.8	-6.9
I_{IH} High-level input current	V_I at V_{CC}			1	μA
I_{IL} Low-level input current	V_I at GND			-1	μA
$I_{OS(H)}$ Short-circuit high-level output current	$V_O = GND$ or V_{SS} ,	See Figure 2 and Note 9		-30	-55
$I_{OS(L)}$ Short-circuit low-level output current	$V_O = GND$ or V_{DD} ,	See Figure 2 and Note 9		30	55
r_o Output resistance	$V_{DD} = V_{SS} = V_{CC} = 0$,	$V_O = -2 \text{ V}$ to 2 V	300		Ω

NOTES:

7. Minimum RS-232 driver output voltages are not attained with ± 5 -V supplies. With V_{DD} less than $V_{CC} + 2 \text{ V}$, the supply currents may increase. For RS-232 compliant output swings and minimum power consumption, $V_{DD} \geq V_{CC} + 2 \text{ V}$.
8. Maximum output swing is nominally clamped at $\pm 6 \text{ V}$ to enable the higher data rates associated with this device and to reduce EMI emissions. The driver outputs may slightly exceed the maximum output voltage over the full V_{CC} and temperature ranges.
9. Not more than one output should be shorted at one time.

driver switching characteristics over operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	UNIT	
t _{PHL}	Propagation delay time, high- to low-level output $R_L = 3 \text{ k}\Omega$ to $7 \text{ k}\Omega$, $C_L = 15 \text{ pF}$, See Figure 1		300	800	1600	ns	
t _{PLH}	Propagation delay time, low- to high-level output $R_L = 3 \text{ k}\Omega$ to $7 \text{ k}\Omega$, $C_L = 15 \text{ pF}$, See Figure 1		300	800	1600	ns	
t _{TLH}	Transition time, low- to high-level output See Figure 1 and Note 10	V _{CC} = 5 V, V _{DD} = 12 V, V _{SS} = -12 V, $R_L = 3 \text{ k}\Omega$ to $7 \text{ k}\Omega$,	Using $V_{TR} = 10\%$ -to-90% transition region, Driver speed = 250 kbit/s, $C_L = 15 \text{ pF}$	375	2240	ns	
		Using $V_{TR} = \pm 3 \text{ V}$ transition region, Driver speed = 250 kbit/s, $C_L = 15 \text{ pF}$	200	1500			
		Using $V_{TR} = \pm 3 \text{ V}$ transition region, Driver speed = 125 kbit/s, $C_L = 2500 \text{ pF}$		2750			
t _{THL}	Transition time, high- to low-level output See Figure 1 and Note 10	V _{CC} = 5 V, V _{DD} = 12 V, V _{SS} = -12 V, $R_L = 3 \text{ k}\Omega$ to $7 \text{ k}\Omega$,	Using $V_{TR} = 10\%$ -to-90% transition region, Driver speed = 250 kbit/s, $C_L = 15 \text{ pF}$	375	2240	ns	
		Using $V_{TR} = \pm 3 \text{ V}$ transition region, Driver speed = 250 kbit/s, $C_L = 15 \text{ pF}$	200	1500			
		Using $V_{TR} = \pm 3 \text{ V}$ transition region, Driver speed = 125 kbit/s, $C_L = 2500 \text{ pF}$		2750			
SR	Output slew rate	V _{CC} = 5 V, V _{DD} = 12 V, V _{SS} = -12 V,	Using $V_{TR} = \pm 3 \text{ V}$ transition region, Driver speed = 0 to 250 kbit/s, $C_L = 15 \text{ pF}$	4	20	30	V/ μ s

NOTE 10: Maximum output swing is limited to $\pm 6 \text{ V}$ to enable the higher data rates associated with this device and to reduce EMI emissions.

receiver electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V _{IT+}	Positive-going input threshold voltage See Figure 3	1.6	2	2.55	V
V _{IT-}	Negative-going input threshold voltage See Figure 3	0.6	1	1.45	V
V _{HYS}	Input hysteresis, $V_{IT+} - V_{IT-}$ See Figure 3	750	1000		mV
V _{OH}	High-level output voltage $I_{OH} = -1 \text{ mA}$	2.5	3.9		V
V _{OL}	Low-level output voltage $I_{OL} = 2 \text{ mA}$		0.33	0.5	V
I _{IH}	High-level input current $V_I = 3 \text{ V}$	0.43	0.6	1	mA
		3.6	5.1	8.3	
I _{IL}	Low-level input current $V_I = 3 \text{ V}$	-0.43	-0.6	-1	mA
		-3.6	-5.1	-8.3	
I _{OS(H)}	Short-circuit high-level output current $V_O = 0$, See Figure 5 and Note 9			-20	mA
I _{OS(L)}	Short-circuit low-level output current $V_O = V_{CC}$, See Figure 5 and Note 9			20	mA
R _{IN}	Input resistance $V_I = \pm 3 \text{ V}$ to $\pm 25 \text{ V}$	3	5	7	k Ω

NOTE 9: Not more than one output should be shorted at one time.

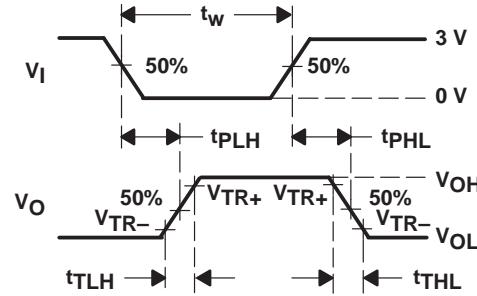
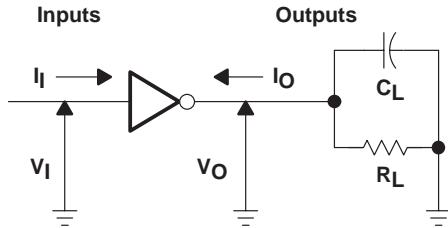
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receiver switching characteristics over operating free-air temperature range, $C_L = 50 \text{ pF}$ (unless otherwise noted) (see Figure 4)

PARAMETER	MIN	TYP	MAX	UNIT
t_{PHL} Propagation delay time, high- to low-level output	400	900		ns
t_{PLH} Propagation delay time, low- to high-level output	400	900		ns
t_{TLH} Transition time, low- to high-level output	200	450		ns
t_{THL} Transition time, high- to low-level output	200	400		ns
$t_{sk(p)}$ Pulse skew $ t_{PLH} - t_{PHL} $	200	425		ns

PARAMETER MEASUREMENT INFORMATION



NOTES: A. The pulse generator has the following characteristics:
 For $C_L < 1000 \text{ pF}$: $t_W = 4 \mu\text{s}$, PRR = 250 kbit/s, $Z_O = 50 \Omega$, $t_f = t_f < 50 \text{ ns}$.
 For $C_L = 2500 \text{ pF}$: $t_W = 8 \mu\text{s}$, PRR = 125 kbit/s, $Z_O = 50 \Omega$, $t_f = t_f < 50 \text{ ns}$.
 B. C_L includes probe and jig capacitance.

Figure 1. Driver Parameter Test Circuit and Waveform

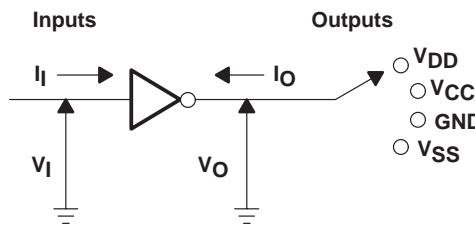


Figure 2. Driver I_{OS} Test

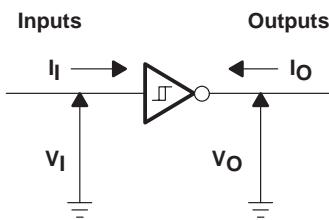
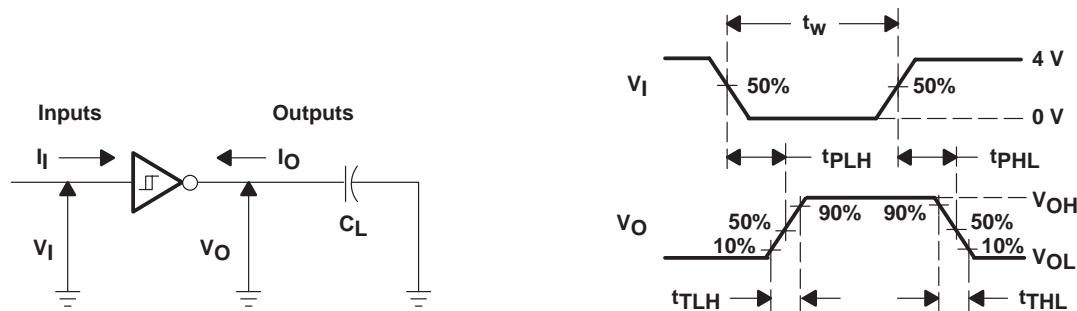


Figure 3. Receiver V_{IT} Test

PARAMETER MEASUREMENT INFORMATION



NOTES: A. The pulse generator has the following characteristics: $t_W = 4 \mu s$, PRR = 250 kbit/s, $Z_O = 50 \Omega$, $t_r = t_f < 50 \text{ ns}$.
B. C_L includes probe and jig capacitance.

Figure 4. Receiver Parameter Test Circuit and Waveform

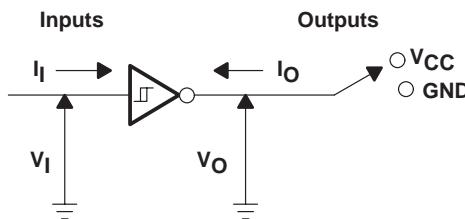


Figure 5. Receiver I_{O_s} Test

APPLICATION INFORMATION

Diodes placed in series with the V_{DD} and V_{SS} leads protect the SN75LP196 in the fault condition in which the device outputs are shorted to ± 15 V and the power supplies are at low voltage and provide low-impedance paths to ground (see Figure 6).

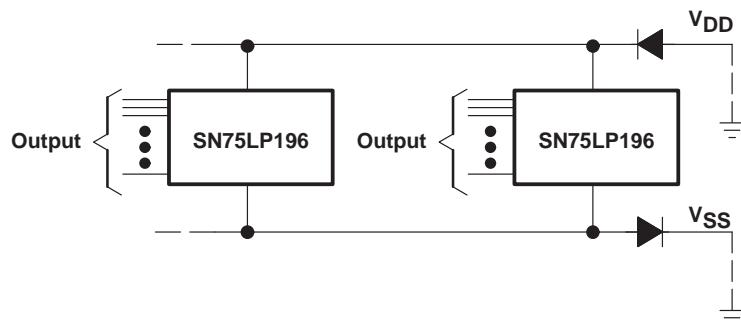


Figure 6. Power-Supply Protection to Meet Power-Off Fault Conditions of EIA/TIA-232-F

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